

Negative Fixed 15V Voltage Regulator in bare die form

Rev 1.0 19/04/19

Description

The 7915AC 15V fixed 3-terminal negative voltage regulator delivers up to 1.5A of output current with adequate heat-sinking. The device is equipped with internal limiting, safe-area compensation + thermal shutdown features for overload immunity. The 7915AC can be used with external components to obtain adjustable voltages or currents & can also be used as the power-pass element in precision high-current voltage regulators. No external components are needed other than to enhance performance or increase design flexibility.

Ordering Information

The following part suffixes apply:

- No suffix MIL-STD-883 /2010B Visual Inspection
- "H" MIL-STD-883 /2010B Visual Inspection+ MIL-PRF-38534 Class H LAT
- "K" MIL-STD-883 /2010A Visual Inspection (Space)
 + MIL-PRF-38534 Class K LAT

LAT = Lot Acceptance Test.

For further information on LAT process flows see below.

www.siliconsupplies.com\quality\bare-die-lot-qualification

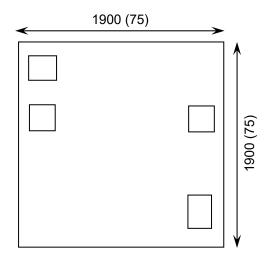
Supply Formats:

- Default Die in Waffle Pack (100 per tray capacity)
- Sawn Wafer on Tape On request
- Unsawn Wafer On request
- Tape & Reel On request
- In Metal or Ceramic package On request

Features:

- ±4% V_{OUT} tolerance over entire temperature range
- Greater than 1A output current capability
- Internal thermal overload protection
- Internal short-circuit current limit
- Output capacitor not essential for stability
- Full military temperature range
- Positive voltage complement is 7815AC

Die Dimensions in µm (mils)



Mechanical Specification

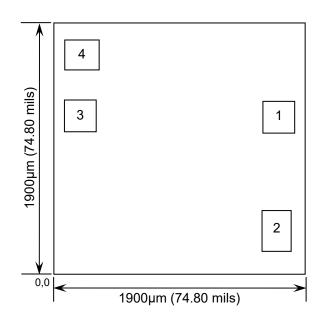
Die Size (Unsawn)	1900 x1900 75 x 75	μm mils		
Minimum Bond Pad Size	230 x 230 9.05 x 9.05	μm mils		
Die Thickness	280 (±20) µr 11.02 (±0.79) mi			
Top Metal Composition	Al 1%Si 1.1μm			
Back Metal Composition	Ti/Ni/Ag 1.2 μm			





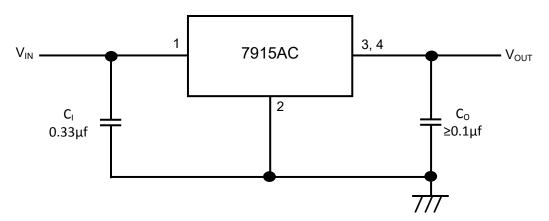
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Pad Layout and Functions



PAD	FUNCTION	COORDINATES (µm)			
IAD		X	Y		
1	V _{IN}	1.575	1.074		
2	GND	1.572	0.188		
3	V _{OUT}	0.088	1.059		
4	V _{OUT}	0.088	1.553		
CONNECT CHIP BACK TO VIN					

Typical Application



 C_l is required if the regulator is located an appreciable distance from power supply filter. C_O is not required for stability; however it does improve transient response. For optimum stability and transient response locate C_l C_O as close as possible to the regulator. A common ground is required between the input and the output voltages. The input voltage must remain typically 2.0 V above the output voltage even during the low point on the input ripple voltage.





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Absolute Maximum Ratings

PARAMETER	SYMBOL	VALUE	UNIT	
Input Voltage	V _{IN}	-35	V	
Power Dissipation ¹	P _D	Internally Limited	W	
Operating Temperature Range	-	-55 to 150	°C	
Maximum Junction Temperature	T _J	150	°C	
Storage Temperature	T _{STG}	-65 to 150	°C	

Recommended Operating Conditions

PARAMETER	SYMBOL	MIN	MAX	UNIT
Input Voltage	V _{IN}	-7	-25	V
Output Current	I _{OUT}	-	1.5	Α
Operating Temperature Range	T _J	-55	125	°C

DC Electrical Characteristics, V_I =-23V, I_{OUT}=500mA,C_I=0.33µF, C_O=0.1µf, T_{MIN}≤T_J≤T_{MAX}(unless noted otherwise)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS	
Output Voltage	V _{OUT}	T _J = 25°C	-14.70	-15	-15.30	V	
		$5\text{mA} \le I_{\text{OUT}} \le 1\text{A},$ -17.9V $\ge V_{\text{IN}} \ge$ -30V, $P_{\text{D}} \le$ 15 Watts	-14.40	-	-15.60		
Line Regulation	ΔV _{OUT}	$-20V \ge V_{IN} \ge -26V, I_{OUT} = 1A, T_{J} = 25^{\circ}C$	-	27	75	mV	
		-20V ≥ V _{IN} ≥ -26V,I _{OUT} = 1A	-	57	150		
		$-17.9V \ge V_{IN} \ge -30V, I_{OUT} = 0.5A$	-	57	150		
		-17.5V≥V _{IN} ≥-30V,I _{OUT} = 1A,T _J = 25°C	-	57	150		
Load Regulation	ΔV _{OUT}	5mA ≤ I _{OUT} ≤ 1.5A,T _J = 25°C	-	68	150		
		250mA ≤ I _{OUT} ≤ 750mA	-	25	75		
		5mA ≤ I _{OUT} ≤ 1A	-	40	150		
Input Bias Current	l _B		-	4.3	7.8	mA	
Input Bias Current Change	Δl _B	-17.5V ≥ V _{IN} ≥ -30V	-	-	0.8		
		5mA ≤ I _{OUT} ≤ 1A	-	0.5 n		mA	
		5mA ≤ I _{OUT} ≤ 1.5A, T _J = 25°C	-	-	0.5		
Output Noise Voltage	V _n	10Hz ≤ f ≤ 100KHz, T _J = 25°C	-	90	-	μV/V _{OUT}	
Ripple Rejection	RR	I _{OUT} = 20mA, f = 120Hz,	-	60	-	dB	
Dropout Voltage	$V_{IN} - V_{OUT}$	I _{OUT} = 1A, T _J = 25°C	-	2	-	V	
Peak Output Current	I _{MAX}	T _J = 25°C	-	2.1	-	Α	
Avg. Output Voltage Temp. Coefficient	TCV _{OUT}	$I_{OUT} = 5\text{mA}, \ 0^{\circ}\text{C} \le T_{J} \le +125^{\circ}\text{C}$	-	-1.0	-	mV/°C	

^{1.} Results in die form are dependent on die attach and assembly method. Max power dissipation is internally limited by the die.





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Typical Characteristics

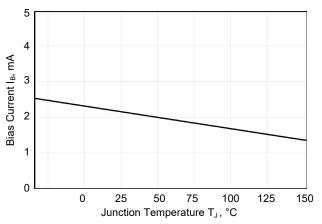


Figure 1 – Bias Current Versus Temperature

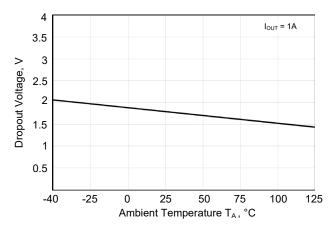


Figure 2 – Dropout Voltage Versus Temperature

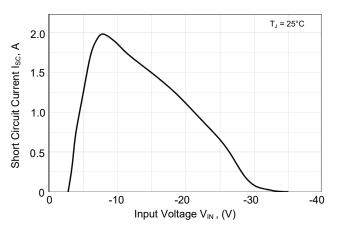


Figure 3 – Short-Circuit Current Versus Input Voltage

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